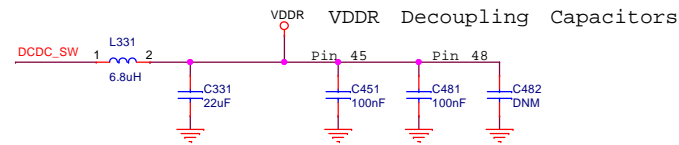
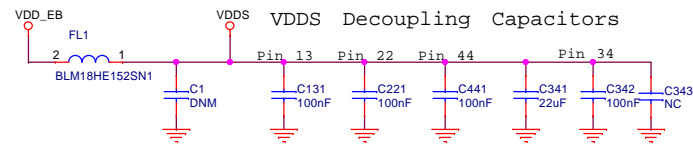
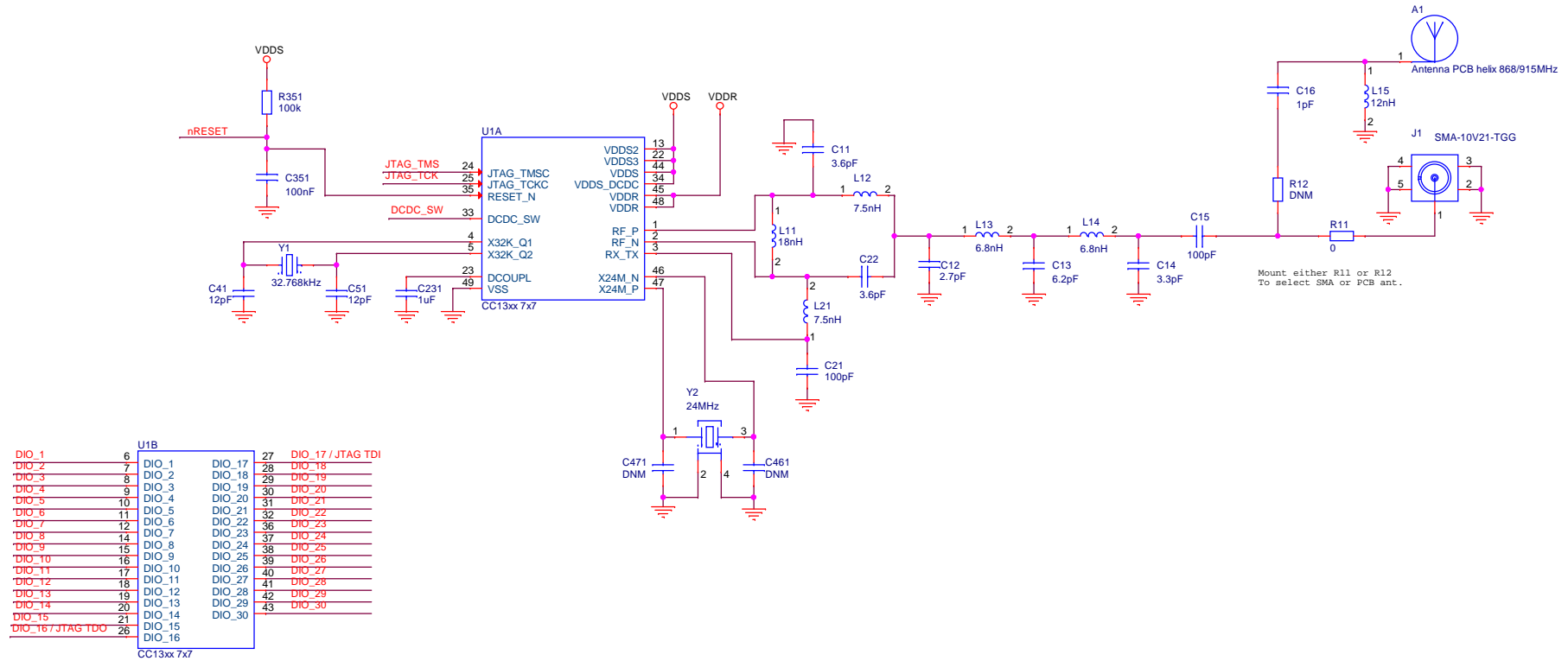


VDDS decoupling capacitors

VDDR decoupling capacitors



Place L331 and C331 close to pin 33.
Low inductance ground for C331



5

4

3

2

1

R 1.0.0

-Initial release revision

R1.0.1

L3 -> Changed from LQG to LQW

L4 -> Changed from LQG to LQW

R1.1.0

-New CC13xx symbol with different DIO to pin mapping

-New Crystal (9 pF, from 7 pF. But 9 pF has been assembled on previous EMs).

-New reference numbers on components.

R1.2.0

- Updating RF filter for better harmonic supression.

- Remove test point on RXTX pin.

R1.3.0

- For PG2

- C15 33pF -> 100pF

- L12, L21 8.2nH -> 7.5nH

- C13 4.7nH -> 6.2nH

- C14 2.2nH -> 3.3nH

R1.3.1


L331 10uH -> 6.8uH

R1.3.2

C341 10uF -> 22uF

R1.3.3

C331 10uF -> 22uF

Title: CC13xxEM-7XD-7793, rev history		 TEXAS INSTRUMENTS	
Drawn: a0132595			
Checked: <Check name>			
Size: A4	Rev: 1.3.3	Sheet: 2 of 2	
Date: Tuesday, August 25, 2015			